# NSN 5962-01-138-6198

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# Maximum Power Dissipation Rating:

500.0 milliwatts

## **Operating Tempurature Range:**

-0.0/+75.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## Features Provided:

W/enable and hermetically sealed and 3-state output and monolithic

## Inclosure Material:

Ceramic

# Inclosure Configuration:

Dual-in-line

## Output Logic Form:

Transistor-transistor logic

## Input Circuit Pattern:

10 input

#### **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

5.5 volts power source

## Time Rating Per Chacteristic:

60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

16 printed circuit

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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